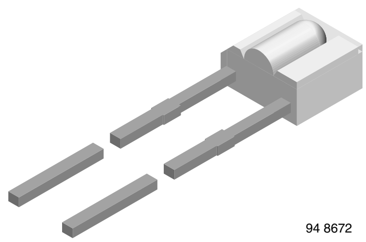
Infrared Emitting Diode, 950 nm, GaAs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DESCRIPTION

TSSS2600 is an infrared, 950 nm emitting diode in GaAs technology, molded in a miniature, clear plastic package with side view lens.

FEATURES

- Package type: leaded
- Package form: side view
- Dimensions (L x W x H in mm): 3.6 x 2.2 x 5
- Peak wavelength: λ_p = 950 nm
- High reliability
- High radiant power
- High radiant intensity
- Angle of half intensity: φ = ± 25°, horizontal
- Low forward voltage
- Suitable for high pulse current operation
- Good spectral matching with Si photodetectors
- Package matched with detector TEST2600
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC

Pb-free
e2
RoHS COMPLIANT
GREEN (5-2008)**

Note
** Please see document "Vishay Material Category Policy": www.vishay.com/doc?99902

APPLICATIONS

- Infrared source in miniature light barriers or reflective sensor systems with short transmission distances and low forward voltage requirements. Matching with silicon PIN photodiodes or phototransistors (e.g. TEST2600)

PRODUCT SUMMARY				
COMPONENT	**I_e (mW/sr)**	**φ (deg)**	**λ_p (nm)**	**tr (ns)**
TSSS2600	2.6	± 25	950	800

Note
- Test conditions see table "Basic Characteristics"

ORDERING INFORMATION			
ORDERING CODE	**PACKAGING**	**REMARKS**	**PACKAGE FORM**
TSSS2600	Bulk	MOQ: 5000 pcs, 5000 pcs/bulk	Side view

Note
- MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS (T_{amb} = 25 °C, unless otherwise specified)				
PARAMETER	**TEST CONDITION**	**SYMBOL**	**VALUE**	**UNIT**
Reverse voltage		V_R	5	V
Forward current		I_F	100	mA
Peak forward current	t_p/T = 0.5, t_p = 100 μs	I_{FM}	200	mA
Surge forward current	t_p = 100 μs	I_{FSM}	2.0	A
Power dissipation		P_V	170	mW
Junction temperature		T_j	100	°C
Operating temperature range		T_{amb}	- 40 to + 100	°C
Storage temperature range		T_{stg}	- 40 to + 100	°C
Soldering temperature	t ≤ 5 s, 2 mm from case	T_{sd}	260	°C
Thermal resistance junction/ambient	Leads not soldered	R_{thJA}	450	K/W

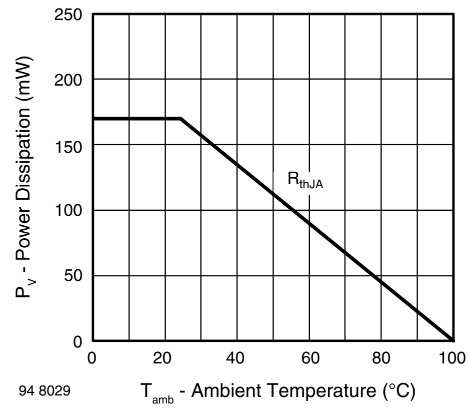


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

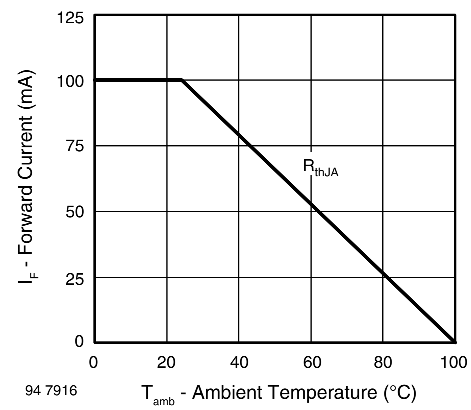


Fig. 1 - Forward Current Limit vs. Ambient Temperature

BASIC CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)						
PARAMETER	**TEST CONDITION**	**SYMBOL**	**MIN.**	**TYP.**	**MAX.**	**UNIT**
Forward voltage	I_F = 100 mA, t_p = 20 ms	V_F		1.25	1.6	V
	I_F = 1.5 A, t_p = 100 μs	V_F		2.2		V
Temperature coefficient of V_F	I_F = 100 mA	TK_{VF}		- 1.3		mV/K
Reverse current	V_R = 5 V	I_R			100	μA
Junction capacitance	V_R = 0 V, f = 1 MHz, E = 0	C_j		30		pF
Radiant intensity	I_F = 100 mA, t_p = 20 ms	I_e	1	2.6	3	mW/sr
	I_F = 1.5 A, t_p = 100 μs	I_e		25		mW/sr
Radiant power	I_F = 100 mA, t_p = 20 ms	ϕ_e		20		mW
Temperature coefficient of ϕ_e	I_F = 100 mA	$TK\phi_e$		- 0.8		%/K
Angle of half intensity	horizontal	φ_1		± 25		deg
	vertical	φ_2		± 60		deg
Peak wavelength	I_F = 100 mA	λ_p		950		nm
Spectral bandwidth	I_F = 100 mA	$\Delta\lambda$		50		nm
Temperature coefficient of λ_p	I_F = 100 mA	$TK\lambda_p$		0.2		nm/K
Rise time	I_F = 100 mA	t_r		800		ns
	I_F = 1.5 A	t_r		400		ns
Fall time	I_F = 100 mA	t_f		800		ns
	I_F = 1.5 A	t_f		400		ns
Virtual source diameter		d		2		mm

BASIC CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

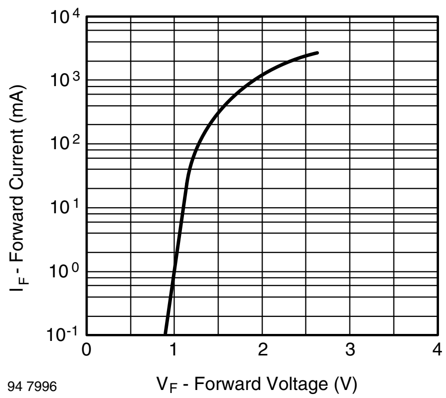


Fig. 2 - Pulse Forward Current vs. Forward Voltage

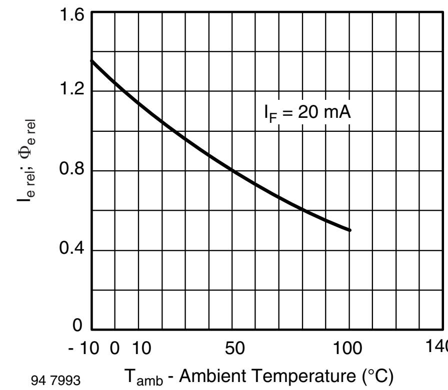


Fig. 5 - Relative Radiant Intensity/Power vs. Ambient Temperature

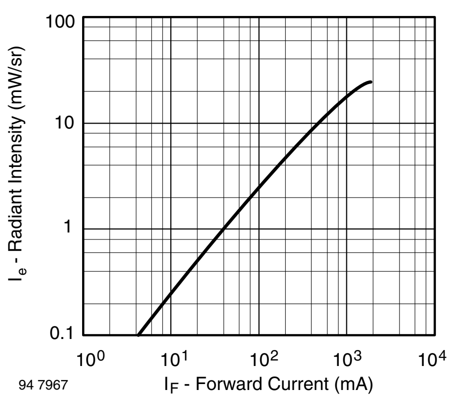


Fig. 3 - Radiant Intensity vs. Forward Current

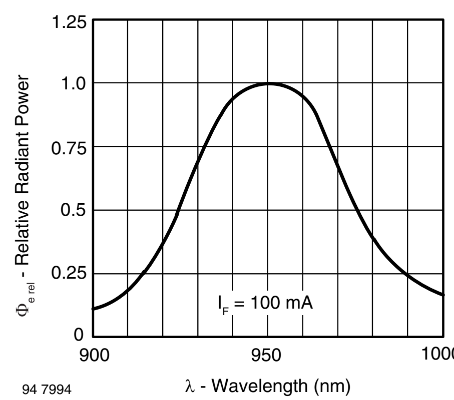


Fig. 6 - Relative Radiant Power vs. Wavelength

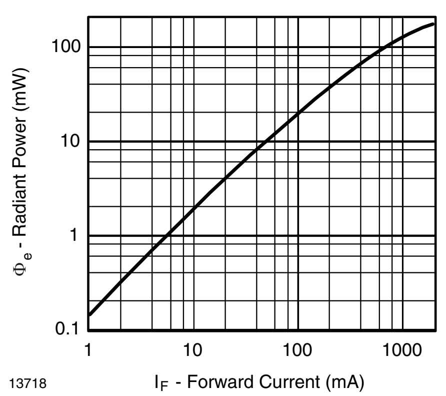


Fig. 4 - Radiant Power vs. Forward Current

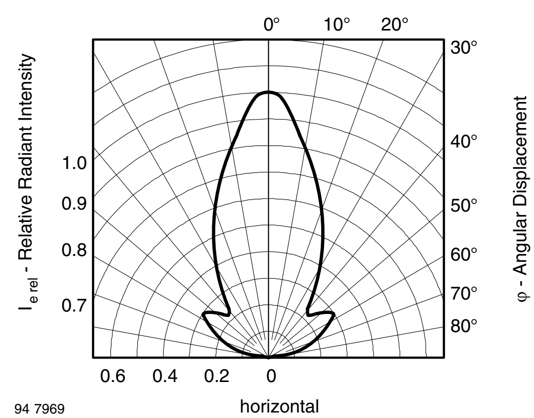


Fig. 7 - Relative Radiant Intensity vs. Angular Displacement

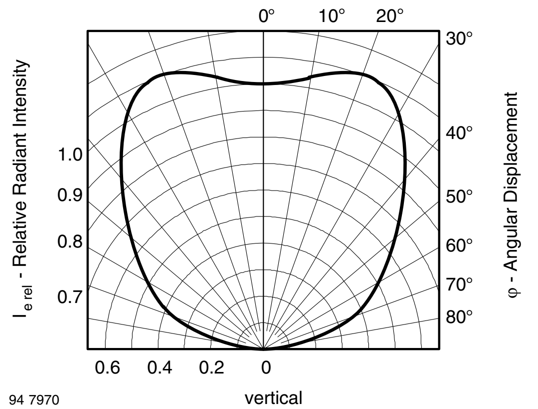
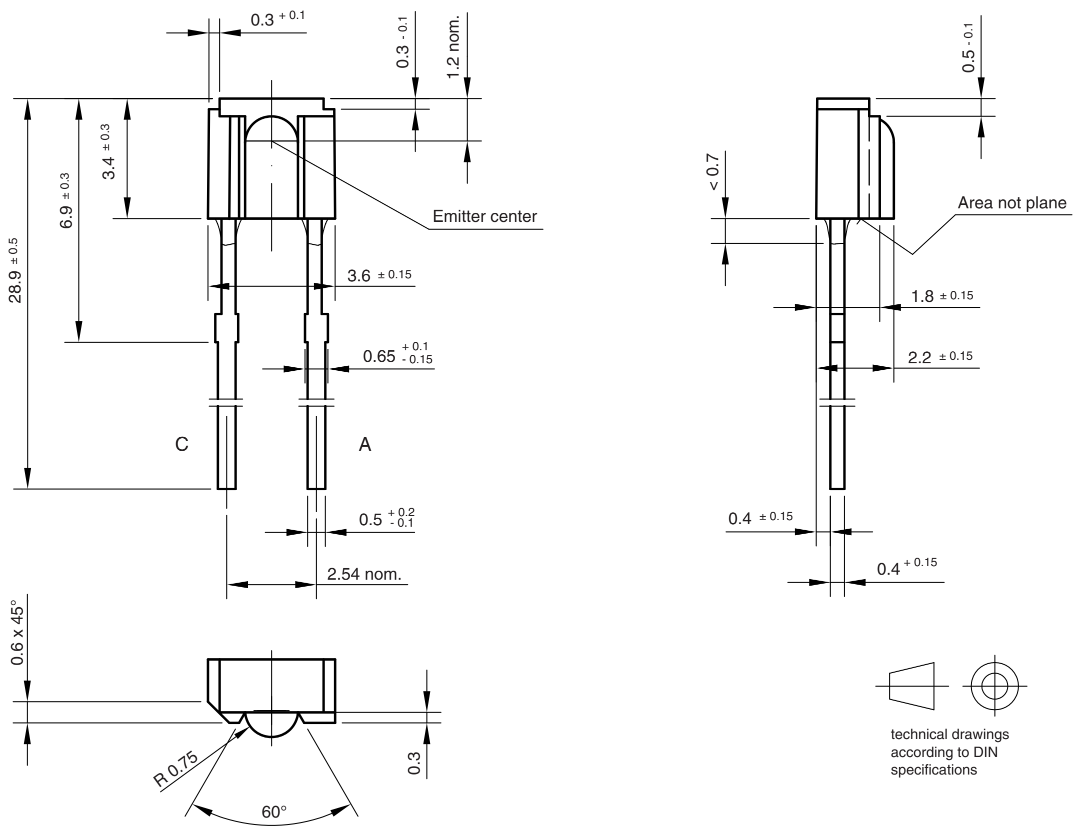


Fig. 2 - Relative Radiant Intensity vs. Angular Displacement

PACKAGE DIMENSIONS in millimeters



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